

Full Material Declaration for attached parts list

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Diotec Semiconductor AG

DUNS number: 330866844

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Declarations authorised by:

Udo Steinebrunner, Product Manager, -

Declaration effective from: 1 October 2020 [Approved on 24 January 2022, 09:23 GMT]

Materials and substances

Use/Location	Material Group	% w/w of material in the part	Substances in the material	CAS Number	% w/w of substance in the material
Chip (die)	Other inorganic materials	7.52%	Silicon	7440-21-3	100%
Die attach	Silver plating	0.55%	1,4-BIS(2,3-EPOXYPROPOXY)BUTANE	2425-79-8	6%
Encapsulation	EP (Epoxy resin)	45.83%	Epoxy resin 89	26335-32-0	12%
			Silver	7440-22-4	82%
			Carbon black	1333-86-4	0.85%
			Phenol	108-95-2	1.15%
			Epoxy resin 89	26335-32-0	2%
			Silica	7631-86-9	9%
			Quartz sand	60676-86-0	87%
Inner preparation	Copper (e.g. copper amounts in cable harnesses)	7.42%	Copper (metallic)	7440-50-8	100%
Leadfinish	Tin plating	7.8%	Tin	7440-31-5	100%
Leadframe	Copper (e.g. copper amounts in cable harnesses)	30.88%	Zinc	7440-66-6	0.1%
			Silver	7440-22-4	0.6%
			Iron	7439-89-6	2.5%
			Copper	7440-50-8	96.8%

Attached parts list

Part number	Part name	Part Mass	Part Mass UoM
QFN3x3	Diode/Transistor Power	0.1	g
